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Note: Bibliography reflects the latest situation

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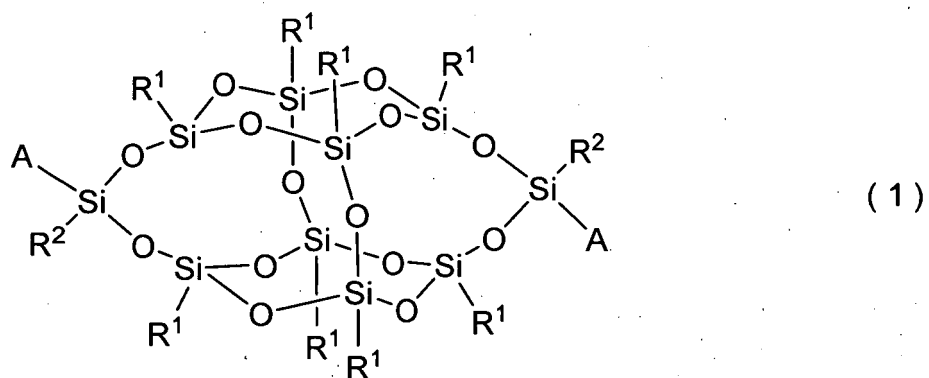
Remarks:

This application was filed on 14 - 08 - 2007 as a
divisional application to the application mentioned
under INID code 62.

(54) **Organosilicon compound**

(57) There is provided a silicon compound represented by Formula (1) :

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wherein A is a group represented by Formula, (2-1):



wherein Z¹ is an alkylene having 3 to 20 carbon atoms, and arbitrary -CH₂- in this alkylene may be replaced by -O-; R³ is hydrogen, an alkyl having 1 to 20 carbon atoms, an aryl having 6 to 20 carbon atoms, or an arylalkyl having 7 to 20 carbon atoms; R⁴ is an alkyl having 1 to 20 carbon atoms, an aryl having 6 to 20 carbon atoms, or an arylalkyl having 7 to 20 carbon atoms; and X¹ is a halogen, and a process for producing said silicon compound represented by Formula (1-1).